# Single 2-Input NOR Gate with Open Drain Output

# MC74VHC1G03, MC74VHC1GT03

The MC74VHC1G03 / MC74VHC1GT03 is a 2-input NOR Gate with an open drain output in tiny footprint packages.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. The output structures also provide protection when  $V_{\rm CC}=0$  V and when the output voltage exceeds  $V_{\rm CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

#### **Features**

- Designed for 2.0 V to 5.5 V V<sub>CC</sub> Operation
- 3.5 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, TSOP-5, SOT-553, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

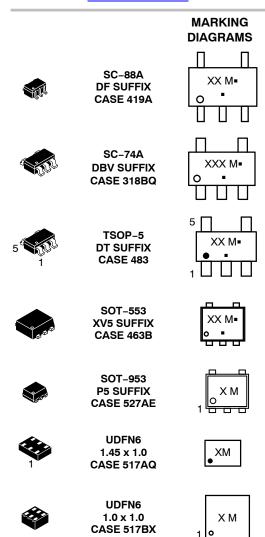


Figure 1. Logic Symbol



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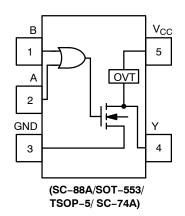
XX = Specific Device Code
M = Date Code\*
= Pb-Free Package

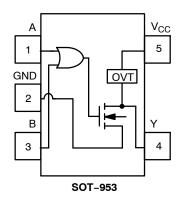
(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.





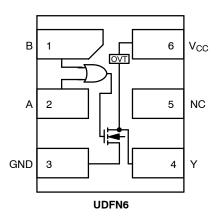


Figure 2. Pinout (Top View)

PIN ASSIGNMENT

(SC-88A/SOT-553/ TSOP-5/SC-74A)

Pin	Function
1	В
2	A
3	GND
4	Y
5	V <sub>CC</sub>

### PIN ASSIGNMENT (SOT-953)

Pin	Function
1	Α
2	GND
3	В
4	Y
5	V <sub>CC</sub>

#### PIN ASSIGNMENT (UDFN)

Pin	Function
1	В
2	Α
3	GND
4	Υ
5	NC
6	V <sub>CC</sub>

#### **FUNCTION TABLE**

Inp	Output	
Α	В	Υ
L	L	Z
L	Н	L
Н	L	L
Н	Н	L

#### **MAXIMUM RATINGS**

Symbol	Characteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage TSOP-5, SC SC-74A, SC-88A, UDFN6, SOT-55		V
V <sub>IN</sub>	DC Input Voltage TSOP-5, SC SC-74A, SC-88A, UDFN6, SOT-55		V
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High o TSOP-5, SC-88A (NLV) Tri-State Mo Power-Down Mode	ode (Note 1) -0.5 to +7.0	V
	DC Output Voltage Active-Mode (High o SC-74A, SC-88A, UDFN6, SOT-553, SOT-953 Tri-State Mode Power-Down Mode	ode (Note 1) -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND -20	mA
I <sub>OK</sub>	DC Output Diode Current	/ <sub>OUT</sub> < GND –20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current	±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin	±50	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs	260	°C
$T_J$	Junction Temperature Under Bias	+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A 377 SC-74A 320 SOT-553 324 SOT-953 254 UDFN6 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A 332 SC-74A 390 SOT-553 386 SOT-953 491 UDFN6 812	mW
MSL	Moisture Sensitivity	Level 1	-
F <sub>R</sub>	Flammability Rating Oxygen Ind	lex: 28 to 34 UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>		Body Model 2000 evice Model 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)	± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Applicable to devices with outputs that may be tri-stated.
 Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
 Tested to EIA/JESD78 Class II.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol		Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	TSOP-5, SC-88A (NLV)	0	V <sub>CC</sub>	V
	DC Output Voltage	SC-74A, SC-88A, UDFN6, SOT-553, SOT-953 Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode ( $V_{\rm CC}$ = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Temperature Ran	ge	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	TSOP-5, SC-88A (NLV) V <sub>CC</sub> = 3.0 V to 3.6 V V <sub>CC</sub> = 4.5 V to 5.5 V	0	100 20	ns/V
	Input Rise and Fall Time	SC-74A, SC-88A, UDFN6, SOT-553, SOT-953 $V_{CC}=2.0\ V$ $V_{CC}=2.3\ V\ to\ 2.7\ V$ $V_{CC}=3.0\ V\ to\ 3.6\ V$ $V_{CC}=4.5\ V\ to\ 5.5\ V$	0 0 0 0	20 20 10 5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS (MC74VHC1G03)

		Test	Vcc	1	Γ <sub>A</sub> = 25°	С	-40°C ≤	T <sub>A</sub> ≤ 85°C	-55°C ≤ T	Γ <sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.5	_	-	1.5	-	1.5	-	V
	Voltage		3.0	2.1	_	-	2.1	-	2.1	-	
			4.5	3.15	-	-	3.15	-	3.15	-	
			5.5	3.85	-	-	3.85	-	3.85	-	
V <sub>IL</sub>	Low-Level Input		2.0	-	_	0.5	-	0.5	-	0.5	V
	Voltage		3.0	-	-	0.9	-	0.9	-	0.9	
			4.5	-	_	1.35	-	1.35	-	1.35	1
			5.5	-	-	1.65	-	1.65	-	1.65	
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36		0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	_	±0.1	-	±1.0	_	±1.0	μΑ
l <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	5.5	_	-	±0.25	-	±2.5	_	± 2.5	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	_	_	1.0	-	10	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	_	1.0	ı	20	_	40	μΑ

#### DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT03)

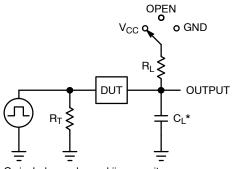
		Test	v <sub>cc</sub>	7	T <sub>A</sub> = 25°	С	-40°C ≤	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.0	-	-	1.0	-	1.0	-	V
	Voltage		3.0	1.4	-	_	1.4	-	1.4	-	
			4.5	2.0	_	-	2.0	_	2.0	_	
			5.5	2.0	_	-	2.0	_	2.0	_	
$V_{IL}$	Low-Level Input		2.0	_	_	0.28	-	0.28	-	0.28	V
	Voltage		3.0	_	_	0.45	-	0.45	-	0.45	
			4.5	_	_	0.8	-	0.8	-	0.8	
			5.5	_	_	0.8	-	0.8	-	0.8	
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{split} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OL} &= 50  \mu\text{A} \\ I_{OL} &= 50  \mu\text{A} \\ I_{OL} &= 50  \mu\text{A} \\ I_{OL} &= 4  m\text{A} \\ I_{OL} &= 8  m\text{A} \end{split}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Cur- rent	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	_	_	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	5.5	_	_	±0.25	-	±2.5	-	± 2.5	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	_	_	1.0	-	10	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	_	40	μΑ
I <sub>CCT</sub>	Increase in Quies- cent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

#### **AC ELECTRICAL CHARACTERISTICS**

				T	A = 25°	С	-40°C ≤ 7	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	5.6	7.9	-	9.5	-	11.0	ns
	(A or B) to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	8.1	11.4	-	13.0	-	15.5	
		C <sub>L</sub> = 15 pF	4.5 to 5.5	_	3.6	5.5	-	6.5	-	8.0	
		C <sub>L</sub> = 50 pF		_	5.1	7.5	-	8.5	-	10.0	
t <sub>PLZ</sub>	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	6.5	9.7	-	11.5	-	14.5	ns
	(A or B) to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	8.1	11.4	-	13.0	-	15.5	
	,	C <sub>L</sub> = 15 pF	4.5 to 5.5	-	4.8	6.8	-	8.0	-	10.0	
		C <sub>L</sub> = 50 pF		_	5.1	7.5	-	8.5	-	10.0	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	-	-	-	-	-	pF

I			Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
	$C_{PD}$	Power Dissipation Capacitance (Note 5)	8.0	pF

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 3. Test Circuit



Figure 4. Switching Waveforms

		V <sub>m</sub>		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

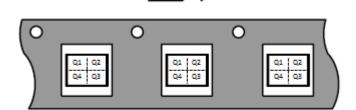
#### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G03DFT1G	SC-88A	VP	Q2	3000 / Tape & Reel
MC74VHC1G03DFT2G	SC-88A	VP	Q4	3000 / Tape & Reel
NLVVHC1G03DFT1G*	SC-88A	VP	Q2	3000 / Tape & Reel
MC74VHC1GT03DFT1G (In Development)	SC-88A	TBD	Q2	3000 / Tape & Reel
MC74VHC1GT03DFT2G (In Development)	SC-88A	TBD	Q4	3000 / Tape & Reel
MC74VHC1G03DBVT1G	SC-74A	VP	Q4	3000 / Tape & Reel
MC74VHC1GT03DBVT1G (In Development)	SC-74A	TBD	Q4	3000 / Tape & Reel
MC74VHC1G03DTT1G	TSOP-5	VP	Q4	3000 / Tape & Reel
MC74VHC1GT03DTT1G (In Development)	TSOP-5	TBD	Q4	3000 / Tape & Reel
MC74VHC1G03XV5T2G (In Development)	SOT-553	TBD	Q4	4000 / Tape & Reel
MC74VHC1GT03XV5T2G (In Development)	SOT-553	TBD	Q4	4000 / Tape & Reel
MC74VHC1G03P5T5G (In Development)	SOT-953	TBD	Q2	8000 / Tape & Reel
MC74VHC1GT03P5T5G (In Development)	SOT-953	TBD	Q2	8000 / Tape & Reel
MC74VHC1G03MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT03MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
MC74VHC1G03MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT03MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	TBD	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# Pin 1 Orientation in Tape and Reel

## Direction of Feed

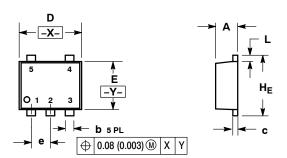


<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### **PACKAGE DIMENSIONS**

#### **SOT-553, 5 LEAD**

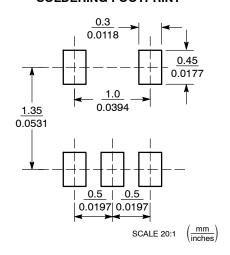
CASE 463B ISSUE C



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.

	М	ILLIMETE	RS		INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
е		0.50 BSC			0.020 BS0	
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

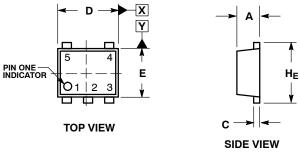
#### **SOLDERING FOOTPRINT\***

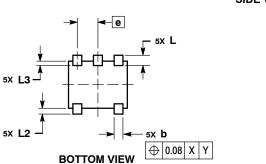


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

SOT-953 CASE 527AE ISSUE E





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

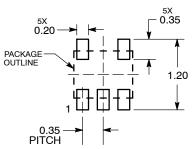
  2. CONTROLLING DIMENSION: MILLIMETERS

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			
DIM	MIN NOM MAX			
Α	0.34	0.37	0.40	
b	0.10	0.15	0.20	
С	0.07	0.12	0.17	
D	0.95	1.00	1.05	
E	0.75	0.80	0.85	
е	0.35 BSC			
HE	0.95	1.00	1.05	
L	0.175 REF			
L2	0.05	0.10	0.15	
L3			0.15	

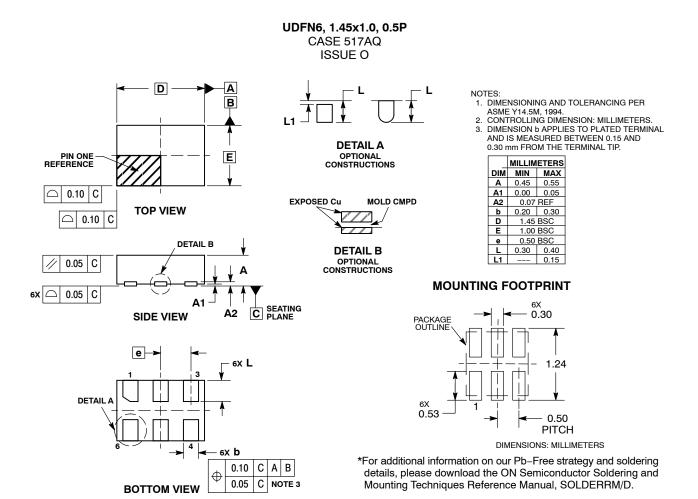
#### **SOLDERING FOOTPRINT\***



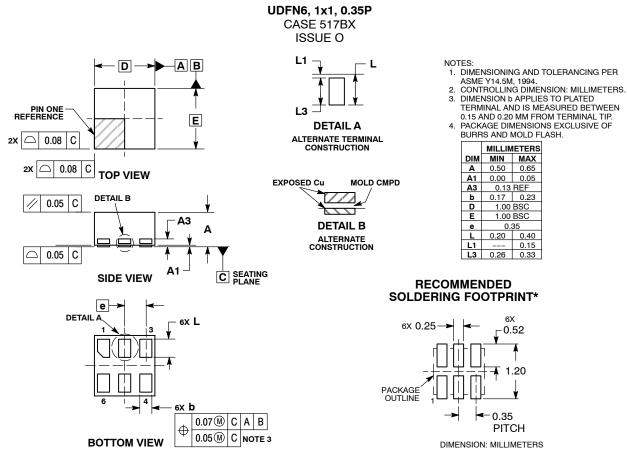
DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**



#### PACKAGE DIMENSIONS



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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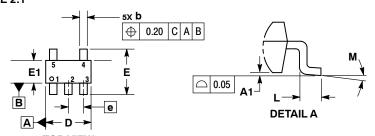
ON Semiconductor Website: www.onsemi.com

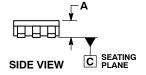
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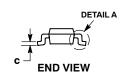
For additional information, please contact your local Sales Representative



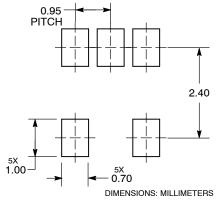
**DATE 18 JAN 2018** 







#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- IES:
  DIMENSIONING AND TOLERANCING PER ASME
  Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE
  MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

	MILLIMETERS			
DIM	MIN MAX			
Α	0.90	1.10		
A1	0.01	0.10		
b	0.25	0.50		
C	0.10	0.26		
D	2.85	3.15		
Е	2.50	3.00		
E1	1.35	1.65		
е	0.95 BSC			
L	0.20	0.60		
М	0° 10°			

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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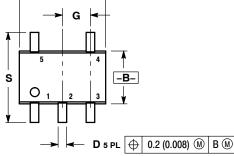
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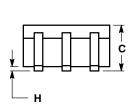


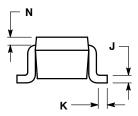
#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

**DATE 17 JAN 2013** 

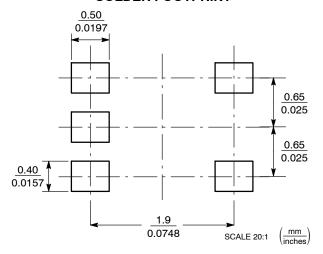








#### **SOLDER FOOTPRINT**



#### NOTES:

- TES:
  DIMENSIONING AND TOLERANCING
  PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
  DIMENSIONS A AND B DO NOT INCLUDE
  MOLD FLASH, PROTRUSIONS, OR GATE
  BURRS.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	<ol><li>COMMON ANODE</li></ol>
3. BASE	3. BASE	3. ANODE 2	<ol><li>SOURCE 1</li></ol>	<ol><li>CATHODE 2</li></ol>
4. COLLECTOR	<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE 2</li></ol>	4. GATE 1	<ol><li>CATHODE 3</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE 1</li></ol>	5. GATE 2	<ol><li>CATHODE 4</li></ol>

5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 4
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

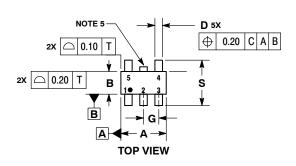
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TSOP-5 **CASE 483 ISSUE N** 

**DATE 12 AUG 2020** 







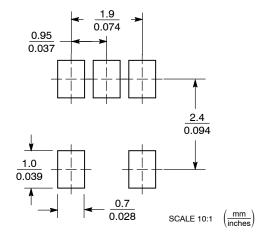


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE
  MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A. OPTIONAL CONSTRUCTION: AN ADDITIONAL
- TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS			
DIM	MIN MAX			
Α	2.85	3.15		
В	1.35	1.65		
C	0.90	1.10		
D	0.25	0.50		
G	0.95	0.95 BSC		
Н	0.01 0.10			
J	0.10	0.26		
K	0.20	0.60		
М	0° 10°			
S	2 50	3.00		

#### **SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***





XXX = Specific Device Code XXX = Specific Device Code

= Assembly Location = Date Code

= Year = Pb-Free Package

= Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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NLV74HC02ADR2G 74HC32S14-13 74LS133 74LVC1G32Z-7 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7

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